## BC817-16/-25/-40

Taiwan Semiconductor

## 300mW, NPN Small Signal Transistor

#### FEATURES

- Low power loss, high efficiency
- Ideal for automated placement
- High surge current capability
- Moisture sensitivity level: level 1, per J-STD-020
- Compliant RoHS
- Halogen-free according to IEC 61249-2-21

KEY PARAMETERS				
PARAMETER	VALUE	UNIT		
V <sub>CBO</sub>	50	V		
V <sub>CEO</sub>	45	V		
V <sub>EBO</sub>	5	V		
Ι <sub>C</sub>	500	mA		
h <sub>FE</sub>	250-600			
Package	SOT-23			
Configuration	Single die			

#### APPLICATIONS

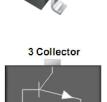
- Switching mode power supply (SMPS)
- Adapters
- Lighting application
- On-board DC/DC converter

#### **MECHANICAL DATA**

- Case: SOT-23
- Molding compound meets UL 94 V-0 flammability rating
- Terminal: Matte tin plated leads, solderable per J-STD-002
- Meet JESD 201 class 1A whisker test
- Weight: 8mg (approximately)

ABSOLUTE MAXIMUM RATINGS (T <sub>A</sub> = 25°C unless otherwise noted)						
PARAMETER	SYMBOL	BC817- 16	BC817- 25	BC817- 40	UNIT	
Marking code on the device		6A	6B	6C		
Power dissipation	PD	300			mW	
Collector-base voltage, emitter open $I_{C} = 10 \ \mu A$ , $I_{E} = 0$		V <sub>CBO</sub>	50			V
Collector-emitter voltage, base open $I_{C} = 10 \text{ mA}, I_{B} = 0$		V <sub>CEO</sub>	45			V
Emitter-base voltage, collector open $I_E = 1 \ \mu A$ , $I_C = 0$		V <sub>EBO</sub>	5			V
Collector current, dc	Ι <sub>C</sub>	500		mA		
Junction temperature	TJ	-55 to +150		°C		
Storage temperature	T <sub>STG</sub>		-55 to +150	)	°C	





1 Base 2 Emitter





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ELECTRICAL SPECIFICATIONS (T <sub>A</sub> = 25°C unless otherwise noted)							
PARAMETER	CONDITIONS		SYMBOL	MIN	ТҮР	МАХ	UNIT
Collector cutoff current, emitter open	V <sub>CB</sub> = 45 V, I <sub>E</sub> = 0		I <sub>CBO</sub>	-	-	0.1	μA
Emitter cutoff current, collector open	V <sub>EB</sub> = 4 V, I <sub>C</sub> = 0		I <sub>EBO</sub>	-	-	0.1	μA
DC current gain	V <sub>CE</sub> = 1 V, I <sub>C</sub> = 100 mA	BC817-16	h <sub>FE</sub>	100	-	250	
		BC817-25		160	-	400	
		BC817-40		250	-	600	
Collector-emitter saturation voltage	I <sub>C</sub> = 500 mA, I <sub>B</sub> = 50 mA		V <sub>CE(sat)</sub>	-	-	0.7	V
Base-emitter saturation voltage	I <sub>C</sub> = 500 mA, I <sub>B</sub> = 50 mA		V <sub>BE(sat)</sub>	-	-	1.2	V
Transition frequency	$V_{CE} = 5 V$ , $I_{C} = 10 mA$ , f= 100MHz		f⊤	100	-	-	MHz

ORDERING INFORMATION				
ORDERING CODE (Note1, 2)	PACKAGE	PACKING		
BC817-XX RF	SOT-23	3K / 7" Reel		
BC817-XX RFG	SOT-23	3K / 7" Reel		

Note:

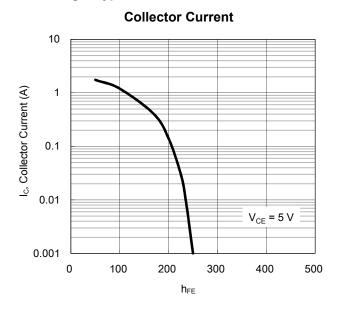
1. "xx" is device code "16", "25" and "40"

2. "G" means green compound (halogen free)

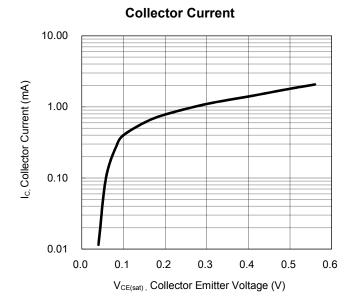


#### **CHARACTERISTICS CURVES**

(T<sub>A</sub> = 25°C unless otherwise noted)

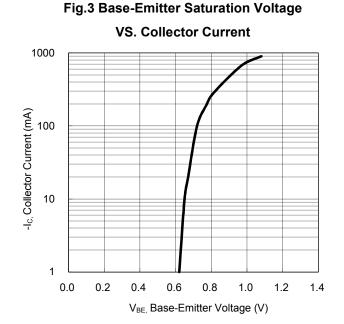


#### Fig.1 Typical Pulsed Current Gain VS. Fig. 2 Coll

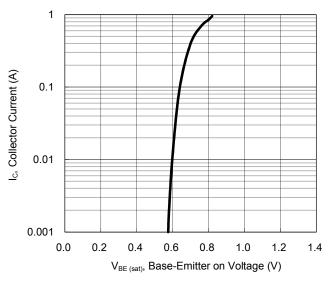


#### Fig. 2 Collector-Emitter Saturation Voltage VS.

## Fig.4 Base-Emitter On Voltage



**VS. Collector Current** 

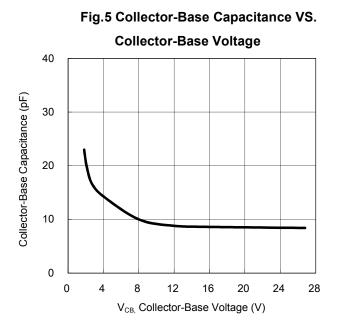




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#### **CHARACTERISTICS CURVES**

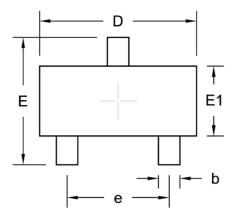
 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$ 



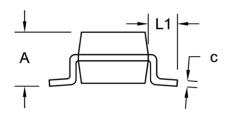
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#### PACKAGE OUTLINE DIMENSION

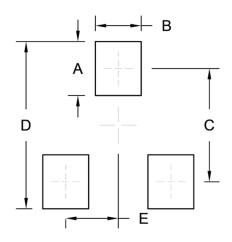
SOT-23



ым	DIM. Unit (mm) Min. Max.		Unit (	(inch)
			Min.	Max.
A	0.89	1.12	0.035	0.044
b	0.30	0.50	0.012	0.020
с	0.08	0.20	0.003	0.008
D	2.80	3.04	0.110	0.120
E	2.10	2.64	0.083	0.104
E1	1.20	1.40	0.047	0.055
е	1.90 BSC		0.07	5 BSC
L1	0.54 REF.		0.021	I REF.



### SUGGESTED PAD LAYOUT



Symbol	Unit (mm)	Unit (inch)
A	1.00	0.039
В	0.85	0.033
С	2.10	0.083
D	3.10	0.122
E	0.98	0.039



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